Analysis of Anisotropic Crystal Growth in Solution using Molecular Modeling Methods

Andreas Voigt^a and Kai Sundmacher^{a,b}

^a Process Systems Engineering, Otto-von-Guericke University Magdeburg, Germany ^b Max Planck Institute for Dynamics of Complex Technical Systems, Magdeburg, Germany



- · Improve the control of size and shape of crystal particles in industrial production processes
- · Enhance the understanding of nucleation and initial growth of crystals from solution at the molecular scale
- · Extract microscopic driving forces for specific and anisotropic crystal shape growth
- Connect driving micromechanics to macroscopic process conditions for production control of crystal shape
- Develop appropriate molecular modeling approaches to bridge the gap between lab theory and real-world production environment



igure 1: Left) Different sizes and shape BaSO₄ crystal products in an "uncontrolled" production (bulk system); Right) Regular size and shape in a "controlled" production (microemulsion system)

Modeling Approach

- · Dynamic Monte Carlo (DMC) simulations are based on a discretization in space and time
- Time discretization is based on different event steps: free Brownian diffusion, surface attachment and surface relocation based on surface energy change
- · Space discretization is based on a basic building block, a crystal growth unit moving in a "hidden" solution
- · Random numbers are used to carry out different events with different units with a certain probability
- · Check of random number generation, proof of statistical evidence and appropriate finite size scaling tests are key to successful Monte Carlo simulations

DMC Procedure

- 1. Brownian diffusion step with all free crystal growth units
- 2. Check for surface attachment of growth units with solute-surface energy
- ΔE_{sol} 3. Attempt relocation step of surface crystal units with surface-surface energy
- ∆E_{surf-s} 4. Consider anisotropy of different crystal faces in energy calculation



 $k_{_B}\cdot T$ $D = \frac{1}{3 \cdot \pi \cdot \eta_{solute} \cdot d_{growth unit}}$

k_B·T



Two-dimensional Systems – 2D



Space discretization with square lattice for 2D DMC ree Brownian diffusion ster b) Lattice relocation to nearest neighbor place



Figure 2: Results for isotropic 2D growth from a simple square seed: Left high temperature, right low temperature



Figure 3: Results for isotropic 2D growth from hexagon and octagon seeds under low temperature conditions

- · Left: Less attachment probability and more relocation probability lead to simple square unit growth.
- Right: Enhanced attachment probability and less relocation probability lead to dendritic growth in fractal fashion - Star-Shape.
- Left: Hexagon seed leads to 6-Star shape. Right: Octagon seed leads to 8-Star shape

Three-dimensional Systems – 3D



Space discretization with square lattice for 3D DMC: a) Free lattice diffusion step

- b) Lattice relocation to nearest neighbor place
- c) Lattice relocation to next-nearest neighbor pla
- d) Lattice relocation to next-next nearest neighbor place





isotropic 3D growth from a cubic seed unit under different growth conditions Left: high temperature, Right: low temperature, Upper: low concentration Lower: high concentration

Figure 4: Results for

Figure 5: Results for anisotropic 3D growth from a cubic seed unit under different growth conditions: Left: high temperature, Right: low temperature Upper: $E_{xy} = 2 E_z$, Lower: $E_{xy} = 1/2 E_z$,



Figure 6: AFM pictures of surface crystal arowth in solution for different crystals.

Future Directions

- · Refine the model parameters to realistic production process conditions
- Extend model variety and lattice geometries to include specific crystal structure growth units
- Specify the surface-energy related steps including results from ab initio and Molecular Dynamics data
- · Compare with experimental data from meso and nano scale crystal growth (AFM)

